Notice of References Cited

Application/Control No

Applicant(s)/Patent Under
Reexamination
BROWN ET AL

Examiner

Art Unit
Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	Α	US-6 198 151	03-2001	Wada	257/520
	В	US-5 943,279	08-1999	Wada	365/205
	С	US-5,329,479	07-1994	Ota et al	365/149
	D	US-5,241,211	08-1993	Tashiro	257/506
	Е	US-4,888,733	12-1989	Mobley	365/145
	F	US-4,641,165	02-1987	lizuka et al.	257/311
	G	US-			
	Н	U Š-			
	ı	US-			
	J	US-			
	К	US-			
	L	US-			
1	М	US-			

FOREIGN PATENT DOCUMENTS

*	Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
N					
0					
Р					
Q					
R					
s					
Т					

NON-PATENT DOCUMENTS

*		Include as applicable: Author. Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Choi, Y-F, et al., "30 nm ultra-thin-body SOI MOSFET with selective deposied Ge raised S/D", June 2000, 58th Dev. Res. Conf. (DRC), pp. 23-4
	V	
	W	
	λ	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY formal are publication dates. Classifications may be US or foreign